

Alessandro Coati SixS beamline - Synchrotron SOLEIL

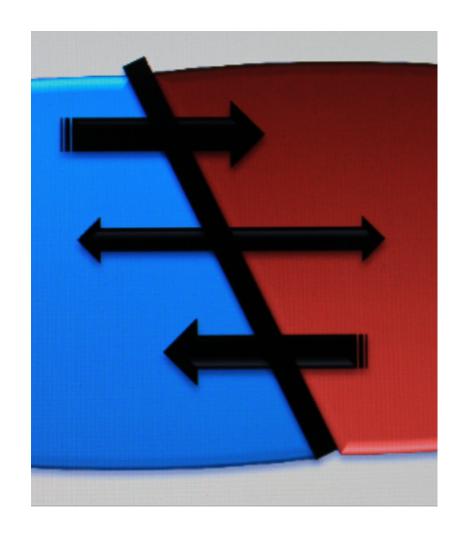
SURFACES, INTERFACES

Definitions

(Oxford English Dictionary)

Interface. A point where two systems, subjects, organizations, etc. meet and interact.

Surface. The outside part or uppermost layer of something.



Surfaces, interfaces and nano-objects

Surfaces as

- interface material vs vacuum
- support of nano-objects

Physical properties (electronic, catalytic, photonics, magnetic):

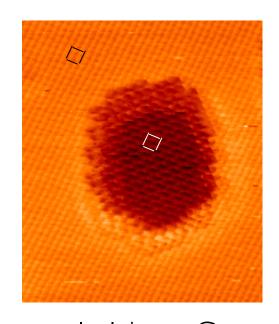
- different from the bulk
- depending on the interface nature (solid/solid, solid/liquid, solid/gaz, liquid/liquid, liquid/gaz)
- depend on the atomic structure, the size, the shape and the organisation at the nanometric scale

X-ray scattering techniques can give information on all these factors

Surface science techniques

Direct Space (STM)

Reciprocal space



IxI bare Cu c(2x2) N/Cu Elmer et al. Surf. Sc.476, 95 (2001) X-rays

 $E=hv=hc/\lambda(Å)=12398/E(eV)$

 λ =1 Å, E=12,4 keV

Abs.length > 100mm $\sigma_a \sim Z^2$ barn

 $n = I - \delta$: GIXD

Coherence width > Imm

Electrons

 $E=p^2/2m = (h/\lambda)^2/2m$ $\lambda(A)=12,265/E^{0.5}(eV)$

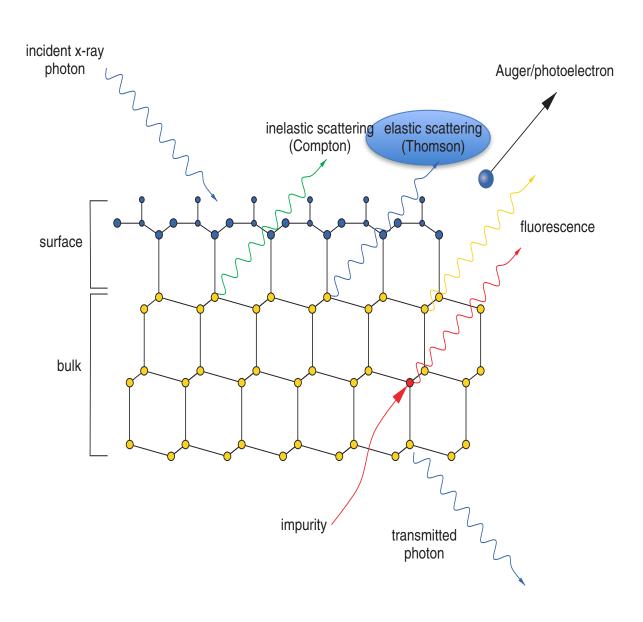
 λ =1 Å, E=150 eV LEED λ =0.1 Å, E=15 keV RHEED

Abs.length | 1 nm (LEED) $\sigma_a \sim 10^8$ barn

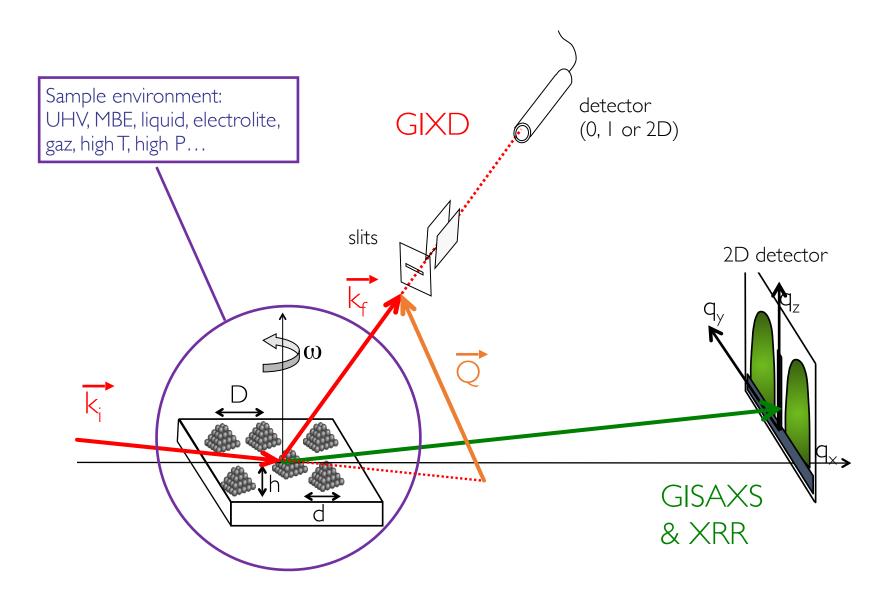
 $n=1+\delta$

Coherence width < 0.1mm

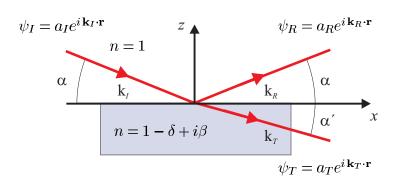
X-RAY-MATTER INTERACTIONS



IN-SITU MEASUREMENTS

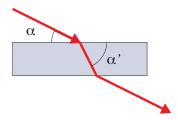


TOTAL REFLECTION



$$cos(\alpha') = n cos(\alpha_i)$$

Light

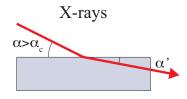


$$n = 1 - \delta + i\beta$$

$$\delta \approx \frac{\lambda}{2\pi} \frac{e^2}{mc^2} \rho_e \approx 10^{-5}$$
 $\beta = \frac{\lambda \mu}{4\pi} \approx 10^{-6}$

$$cos(\alpha_c) = Re(n) = I - \delta$$

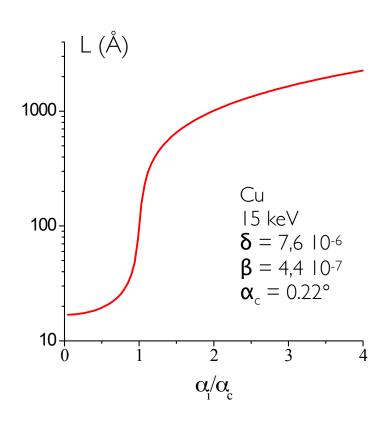
$$\alpha_c \approx \sqrt{2\delta} \approx 10^{-3} \text{ rad}$$





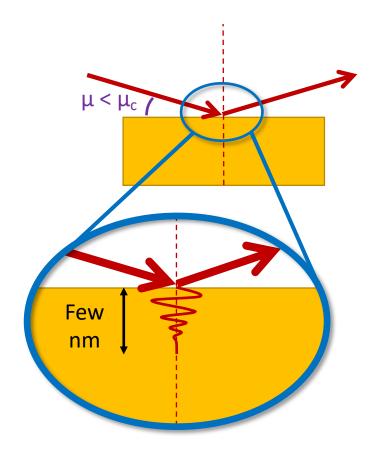
Total external reflection

PENETRATION DEPTH

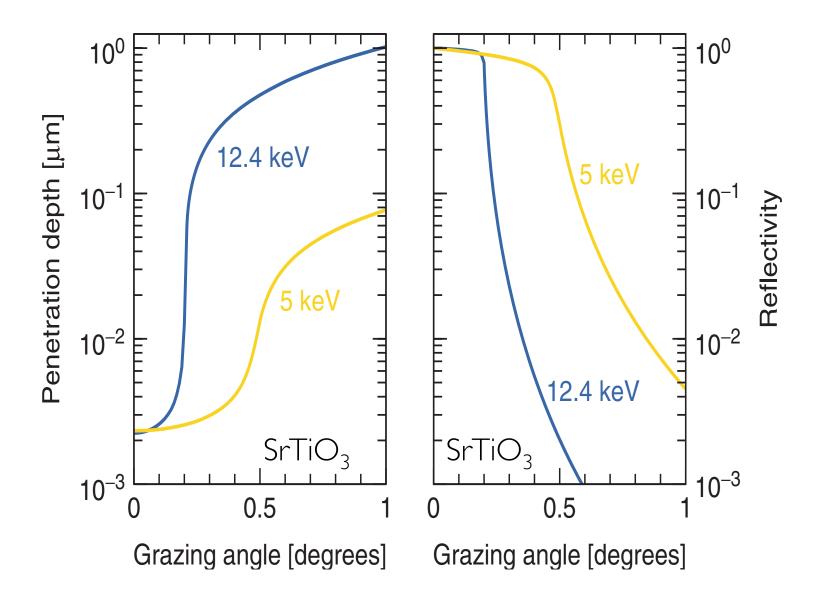


$$\frac{\mathbf{\alpha_i}}{\mathbf{L} \, (\mathbf{\mathring{A}})} = \frac{0.1 \, \alpha_c}{15} = \frac{2 \, \alpha_c}{100}$$

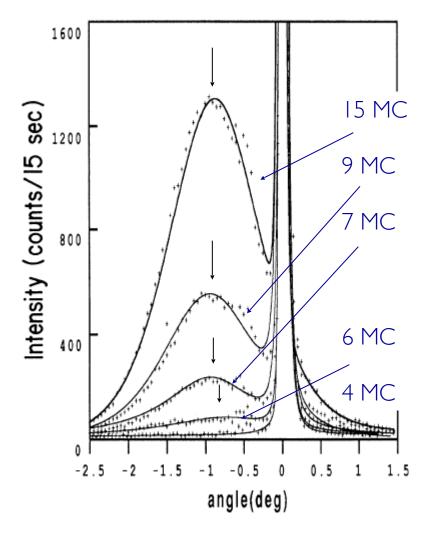
$$L \approx \frac{-\lambda}{4\pi \operatorname{Im} \sqrt{\alpha_{i}^{2} - \alpha_{c}^{2} - 2i\beta}}$$



PENETRATION DEPTH



ZNTE/GAAS



$$\frac{a_{ZnTe} - a_{GaAs}}{a_{GaAs}} = 7,9\%$$

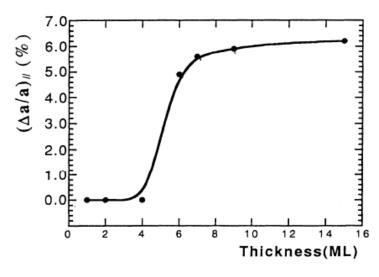


FIG. 2. Variation of $(\Delta a/a)_{\parallel}$ with the film thickness.

FIG. 1. θ -2 θ scans of the (200) reflection from ZnTe/GaAs (001) for heterostructures of increasing thicknesses (4, 6, 7, 9, and 15 ML from bottom to top curve). Profiles are aligned on the substrate Bragg peak.

V. H. Etgens et al. Phys. Rev. B47, 10607 (1993)

ZNTE/GAAS

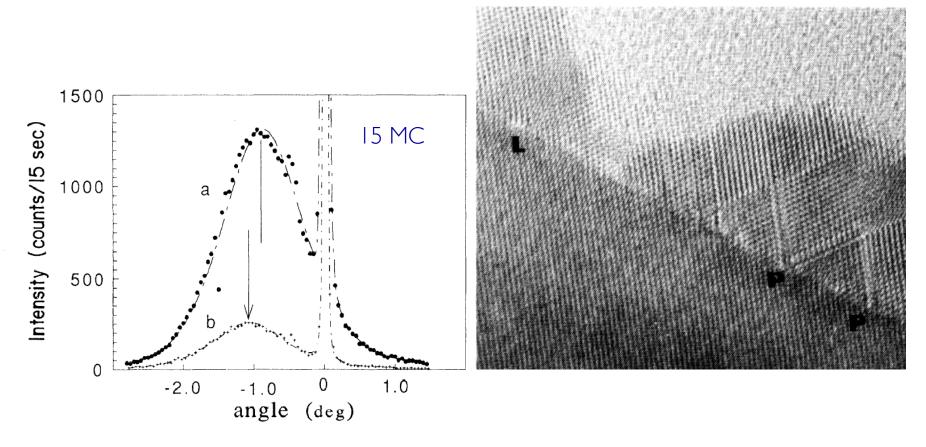
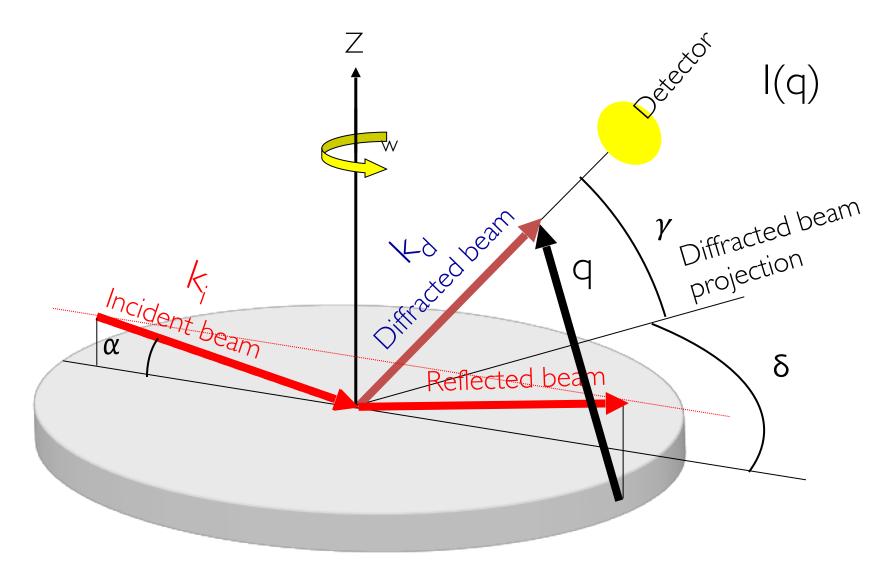


FIG. 6. Radial scans of the 15-ML ZnTe/GaAs at different inside angles. (curve a) $\alpha = \alpha_c$; (curve b) $\alpha = 0.3\alpha_c$.

DATA COLLECTION GEOMETRY



Scattering Vector: $q = k_d - k_i$

Expression of the scattering intensity

$$I(q) = |A(q)|^{2} \propto \left| \int_{\infty} d^{3}r \rho(r) \exp(iq \cdot r) \right|^{2}$$

Kinematic approximation

Decomposition: crystal description

$$f_{atome}(q) = \int d^3r \ \rho_{atome}(r) \ e^{-iq.r}$$

Atomic scattering factor

$$F_n(q) = \sum_i f_j e^{-iq.r_j} = TF[unit cell]$$

Structure Factor

$$A(q) = \sum_{n} \sigma(R_n) F_n(q) e^{-iq \cdot R_n}$$

Lattice vector: R_n

Crystal shape : $\sigma(r)$

Perfectly ordered structure:

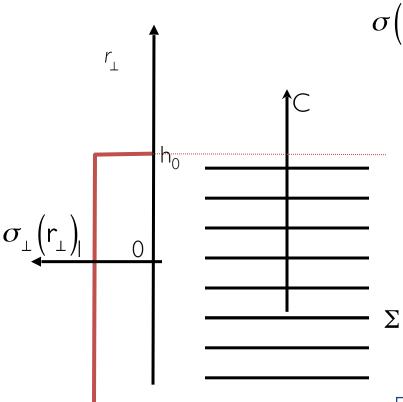
$$F_n(q) = F(q)$$

The intensity diffused by the crystal is:

the atomic form factor is a complex quantity of q = f(q) + f' + if represent the dispersion and absorption corrections, they take significant values in a close vicinity of absorption edges of the considered atom (another leaves of the size effects)

Finite size effects

SEMI-INFINITE CRYSTAL



$$\sigma(r) = \sigma_{//}(r_{//}) \quad \sigma_{\perp}(r_{\perp}) \quad \text{where} \quad \sigma_{//}(r_{//}) = 1$$

$$\sigma_{\perp}(r_{\perp}) = 1 \quad \text{pour} \quad r_{\perp} < h_{0}$$

$$\sigma_{\perp}(r_{\perp}) = 0 \quad \text{pour} \quad r_{\perp} > h_{0}$$

Fourier transform of
$$\sigma(r)$$
:
$$\sum_{n=-\infty}^{+\infty} \frac{1}{\left(q_{\perp} - n c^*\right)^2} = \left(\frac{\pi}{c^* \sin(\pi L)}\right)^2$$

$$\Sigma(q) = \frac{e^{-iq_{\perp}.h_0}}{-iq_{\perp}} \delta(q_{//}) \implies \left|\Sigma(q)\right|^2 = \frac{1}{q_{\perp}^2} \delta(q_{//})$$

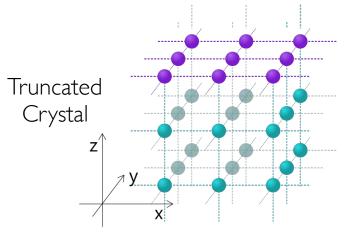
$$I(q) = \frac{|F(q)|^2}{s^2} \left(\frac{1}{2\sin(\pi I)}\right)^2 \left[\sum_{G_{//}} \delta(q_{//} - G_{//})\right]$$

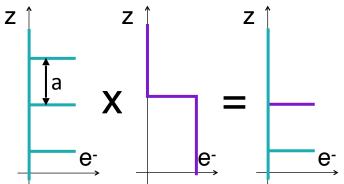
Crystal Truncation Rods (CTR): issued from Bragg peak & perpendicular to the surface

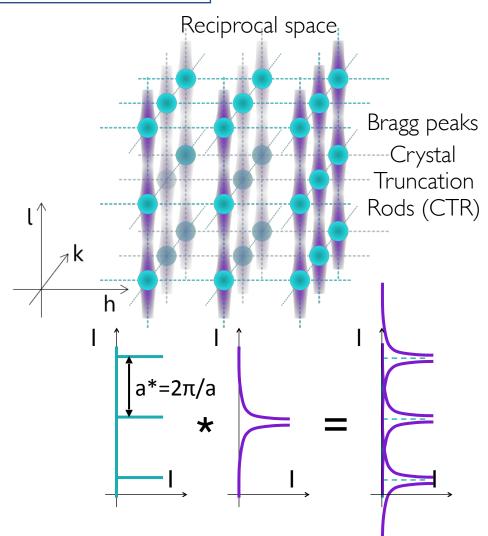
CRISTAL TRUNCATION ROD (CTR)

$$I(q) = \frac{\left|F(q)\right|^2}{s^2} \left(\frac{1}{2\sin(\pi I)}\right)^2 \left[\sum_{G_{//}} \delta(q_{//} - G_{//})\right]$$

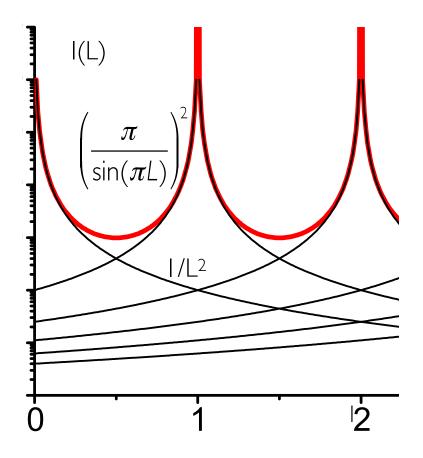






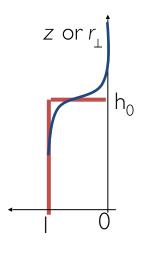


CRISTAL TRONCATION ROD (CTR)



$$\sum_{n=-\infty}^{+\infty} \frac{1}{\left(q_{\perp} - n c^{*}\right)^{2}} = \left(\frac{\pi}{c^{*} \sin(\pi L)}\right)^{2} \qquad q_{\perp} = Lc^{*}$$

Surface roughness



$$\sigma_{\perp}^{surf}(\mathbf{r}_{\perp}) = 1$$
 for $r_{\perp} < h_0$

$$\sigma_{\perp}^{surf}(\mathbf{r}_{\perp}) = 0$$
 for $r_{\perp} > h_0$

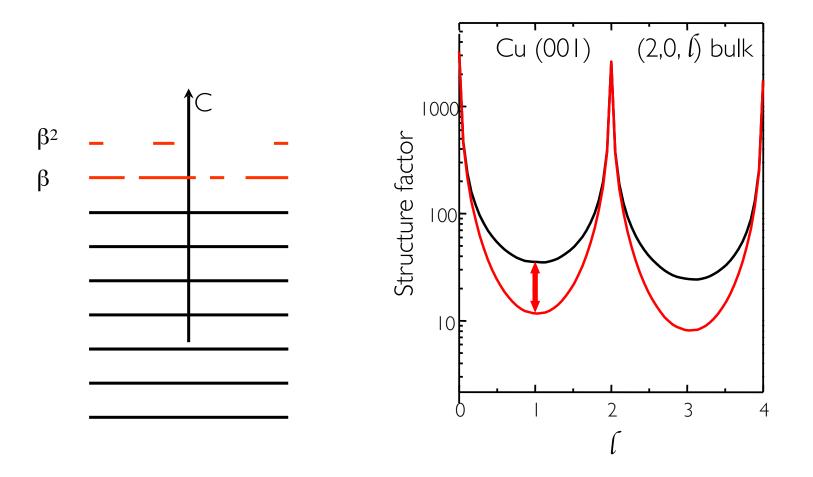
$$\sigma_{\perp}^{\text{surf. rgh.}}(\mathbf{r}_{\perp}) = \sigma_{\perp}^{\text{surf}}(\mathbf{r}_{\perp}) \otimes g(\mathbf{r}_{\perp})$$

$$\left| \mathbf{\Sigma}^{\text{surf.rgh.}} \left(\mathbf{q}_{\perp} \right) \right|^2 = \frac{1}{q_{\perp}^2} \left| \text{TF} \left[g \left(\mathbf{r}_{\perp} \right) \right] \right|^2$$

The Intensity decays more rapidly from the reciprocal node than for a flat surface Roughness models:

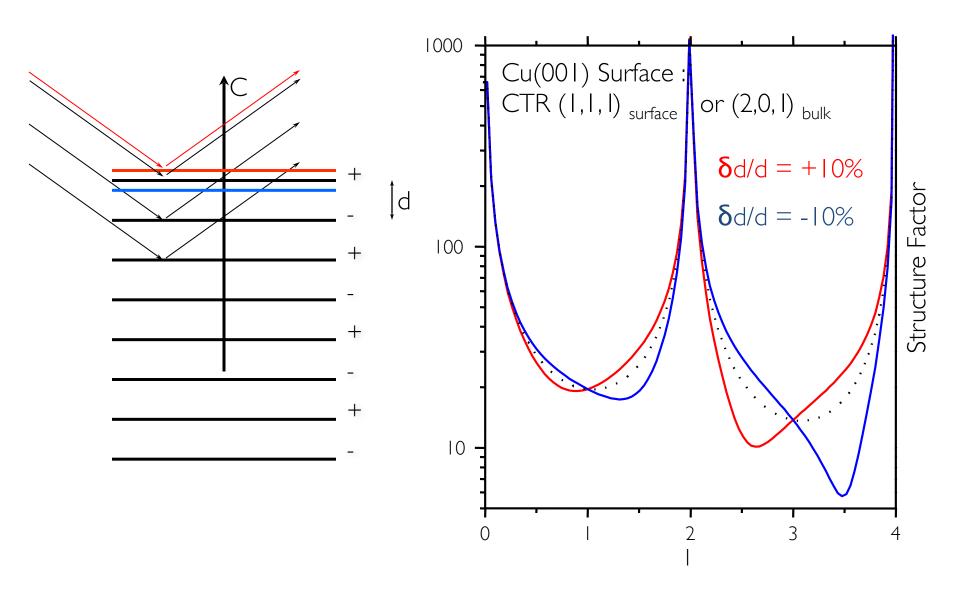
- i. a simple two level model (E.Vlieg)
- i. an exponential decay (I. Robinson)
- iii. a gaussian distribution of successive layers occupancy (P. Guenard)

CTR FROM A ROUGH SURFACE

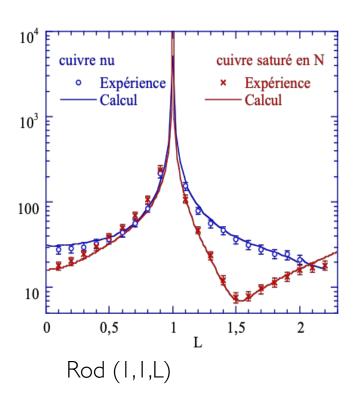


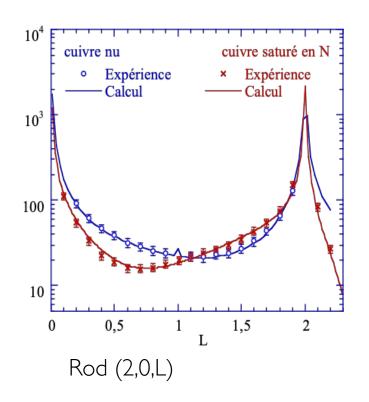
Optimal sensitivity in « anti-bragg » position, used to monitor layer by layer growth through pseudo-periodic oscillations

CTR: EFFECT OF THE RELAXATION



CTR: CU (001) ET N/CU(001)





	bare Cu	saturated Cu(q = I)	
Relaxation d ₁₂	-3,16%	+13,54%	
Relaxation d ₂₃	-0,54%	+1,46%	

CTR AND INTERFACES

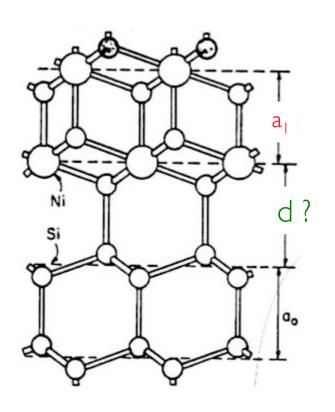
SiNi₂/Si(111) interface

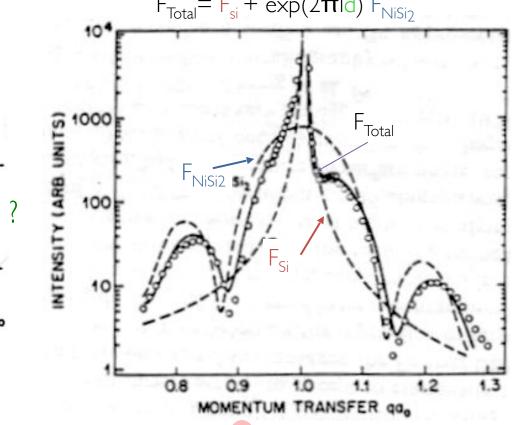
around Si(111) Bragg peak

 $F_{Total} = F_{si} + exp(2\pi Id) F_{NiSi2}$

NiSi₂ Structure and thickness known

Si(111) structure known





Adjustment
$$\rightarrow$$
 $\frac{d}{a_o} = 1.10 \pm 0.02$

$$\frac{a_1}{a_0} = 0.996 \pm 0.003$$

$$\sigma(r) = \sigma_{//}(r_{//}) \quad \sigma_{\perp}(r_{\perp}) \quad \text{where} \quad \sigma_{//}(r_{//}) = 1$$

$$\sigma_{II}(\mathbf{r}_{II}) = \mathbf{I}$$

Fourier transform of $\sigma(r)$:

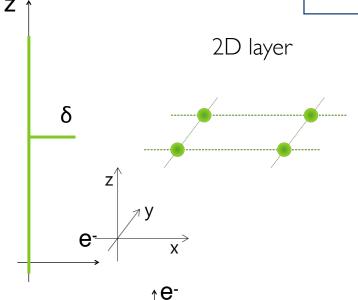
$$\sigma_{\perp} \left(\mathbf{r}_{\perp} \right) = \delta(\mathbf{r}_{\perp})$$

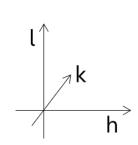
$$\Sigma(q) = const \delta(q_{//}) =$$

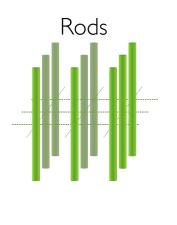
$$\sigma_{\perp}(\mathbf{r}_{\perp}) = \delta(\mathbf{r}_{\perp})$$
 $\Sigma(\mathbf{q}) = const \delta(\mathbf{q}_{\parallel}) \implies |\Sigma(\mathbf{q})|^2 = const^2 \delta(\mathbf{q}_{\parallel})$

$$I(q) = \frac{\left|F(q)\right|^2}{s^2} const^2 \left[\sum_{G_{//}} \delta(q_{//} - G_{//})\right]$$

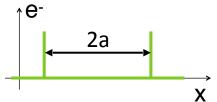
Reciprocal space

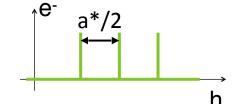






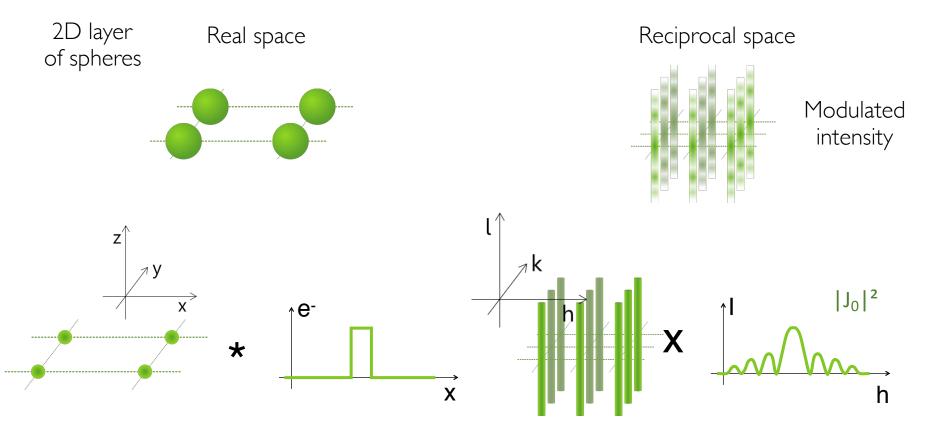




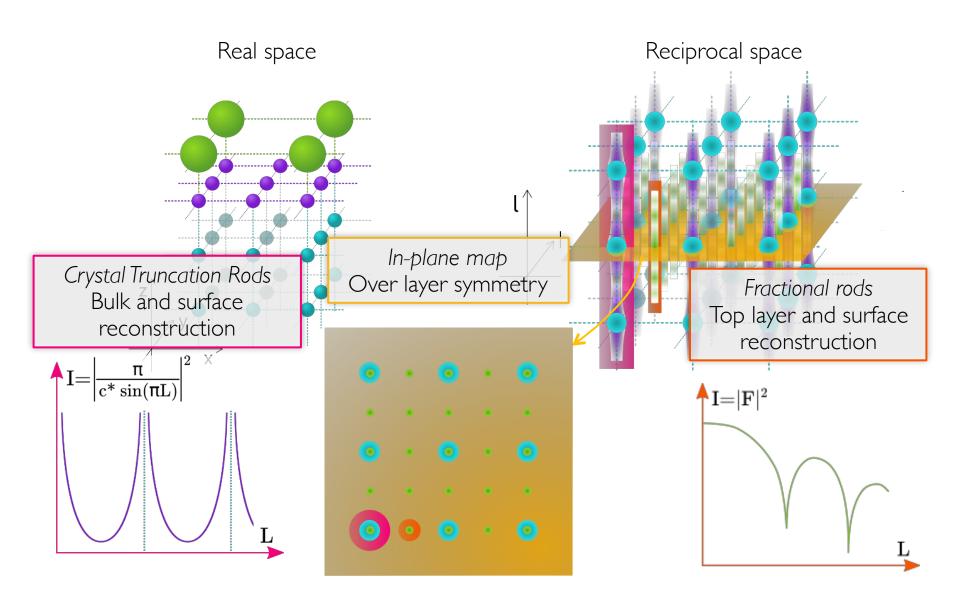


2D crystal

$$I(q) = \frac{\left|F(q)\right|^2}{s^2} const^2 \left[\sum_{G_{//}} \delta(q_{//} - G_{//})\right]$$



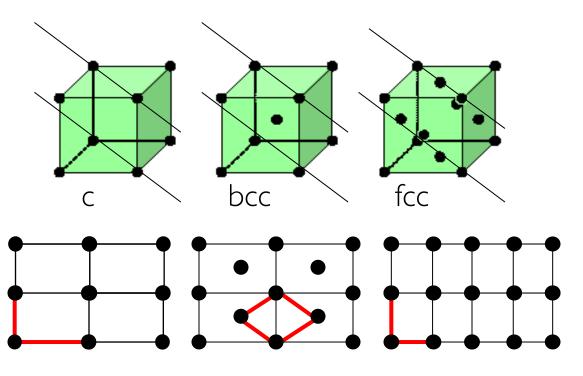
SURFACE X-RAY DIFFRACTION



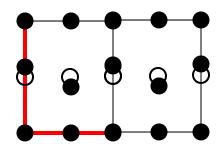
SURFACE CRYSTALLOGRAPHY

Ex: (110) cut in the 3 cubic lattices

Basis vectors \mathbf{a}_s \mathbf{b}_s of the $|\mathbf{x}|$ surface cells

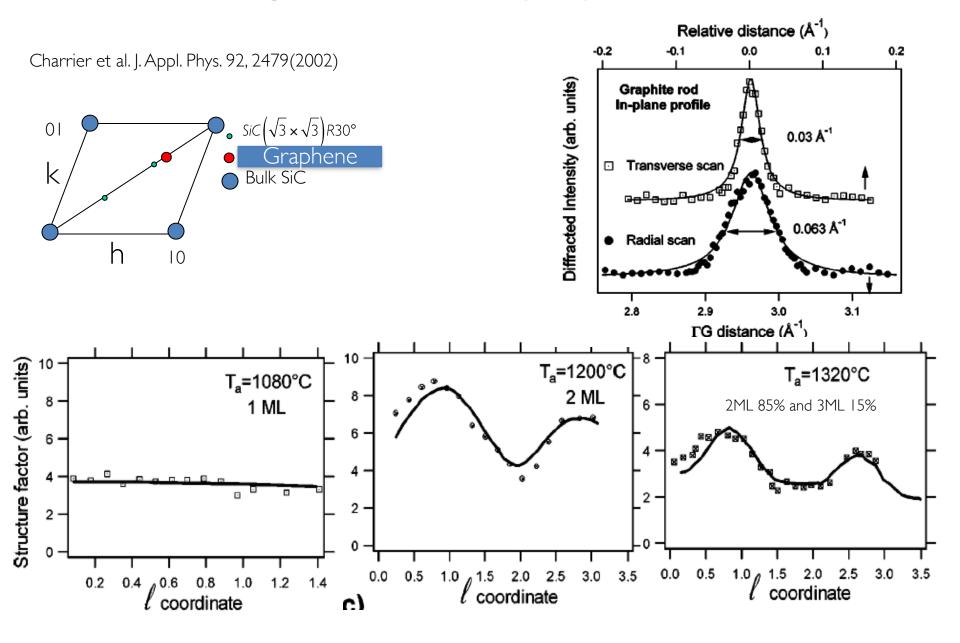


Basis vectors of a 2x2 unit cell on a reconstructed (110) surface of an fcc lattice

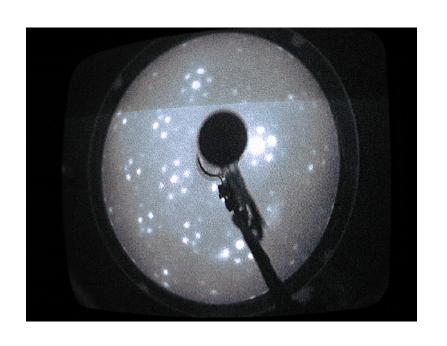


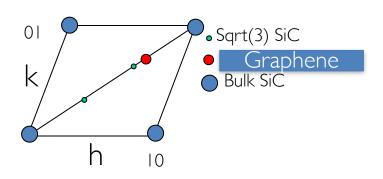
More generally MXN reconstruction

GRAPHENE GROWTH



LEED VS GIXD





apparent
$$\left(6\sqrt{3}\times6\sqrt{3}\right)$$

A fully relaxed graphene plane in registry with the SiC substrate

Multiple scattering

versus

single scattering

ROD SOFTWARE

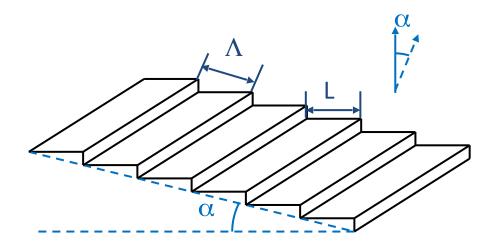
The « ROD » code

E.Vlieg, J. Appl. Cryst, 33, 401 (2000) → interactive webpage ANA-ROD

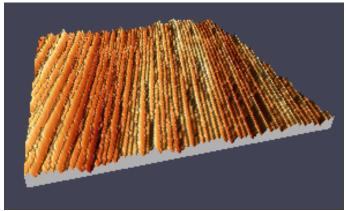
http://www.esrf.fr/computing/scientific/joint_projects/ANA-ROD/index.html



VICINAL SURFACE

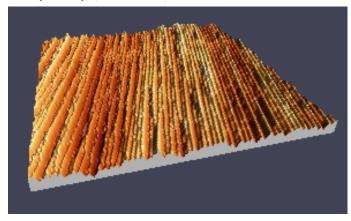


Cu(433) (100x100) nm

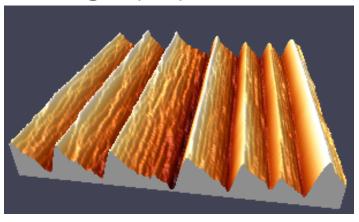


SELF ORGANISATION: AG/CU

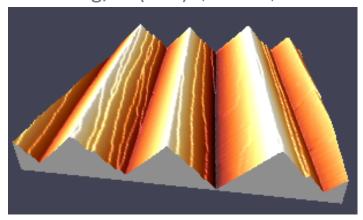
Cu (433) (100x100) nm



0.3 ML Ag/Cu(433) (200x200) nm

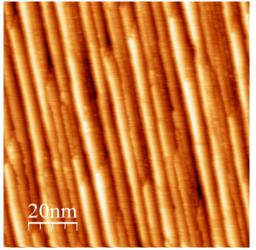


0.6 ML Ag/Cu(433) (200x200) nm



SELF ORGANISATION: AG/NI

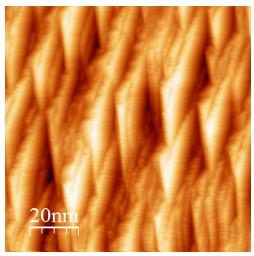
Ag/Ni(11 9 9)

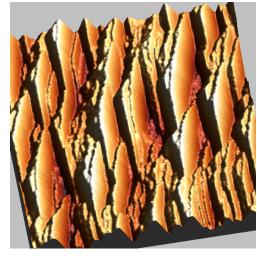




Organisation ID

Ag/Ni(27 17 19)

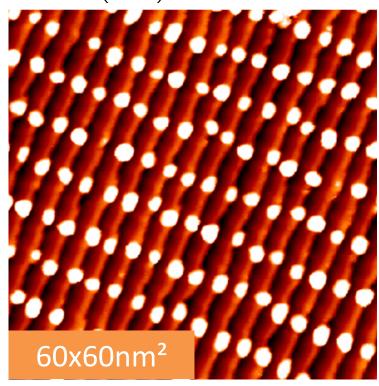




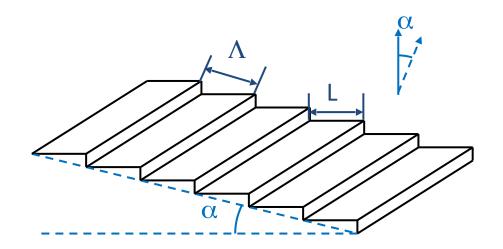
Organisation 2D

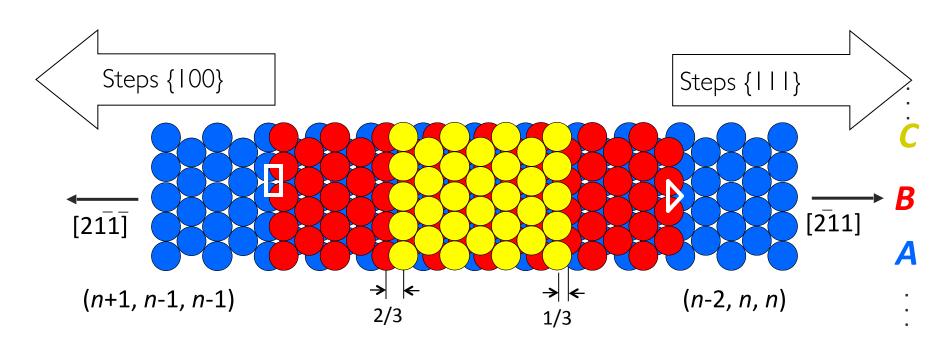
SELF ORGANISATION: CO/AU

Co/Au(788)



VICINAL SURFACES (111) FCC

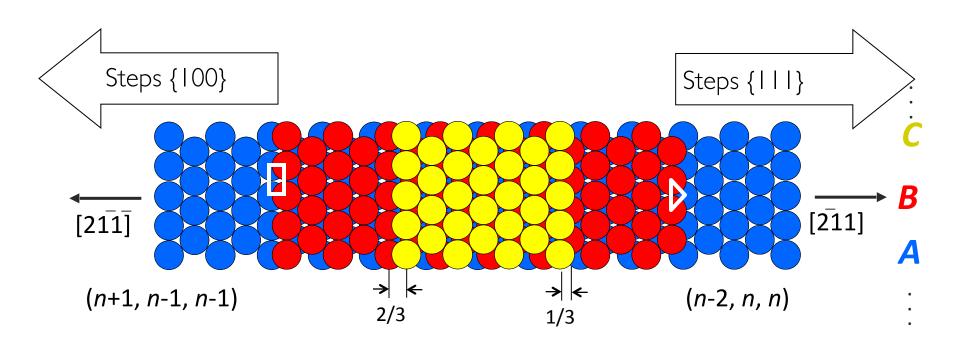




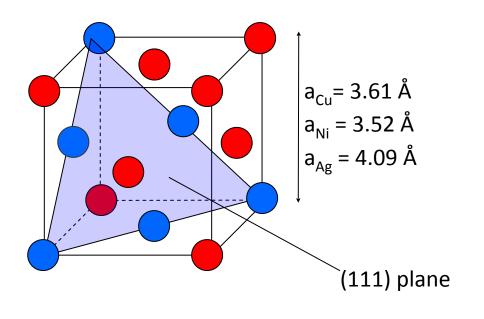
VICINAL SURFACES (111) FCC

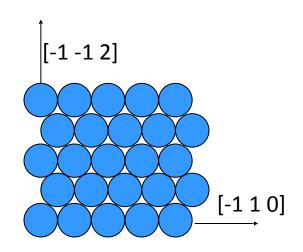
	Angle (°)	Lines	Λ
			(nm)
Cu(211)	(-)19.5	2+2/3	0.626
Au(322)	(-) .4	4+2/3	1.17
Ni(1199)	(-) 5.57	9+2/3	2.096

	Angle (°)	Lines	٨
			(nm)
Au(233)	10.0	5+1/3	1.33
Ag(133)	22.0	2+1/3	0.629
Ag(799)	6.46	8+1/3	2.095



"MODEL SYSTEMS": AG/CU, AG/NI



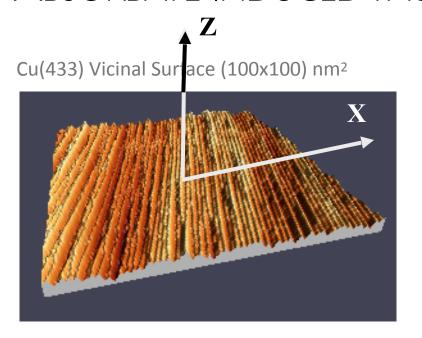


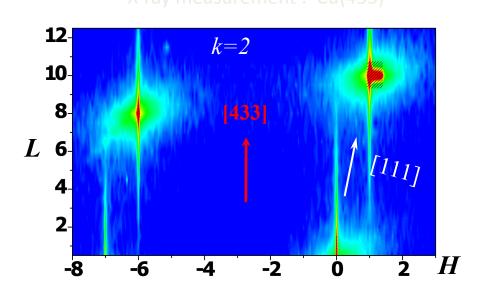
- fcc structure
- Immiscibles
- atomic radii
- cohesion energies :

$$r_{Ag}/r_{Cu} = 1,13$$
 $r_{Ag}/r_{Ni} = 1,15$ $E_{NCu} = -3,50 \text{ eV}$ $E_{cNi} = -4,44 \text{ eV}$ $E_{cAg} = -2,96 \text{ eV}$

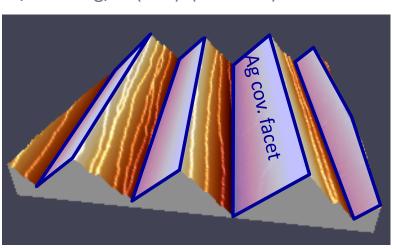
Ag segregates on Ni or Cu Abrupt Interfaces

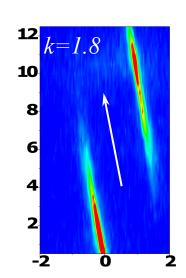
ABSORBATE INDUCED FACETING: X-RAY MEASUREMENTS

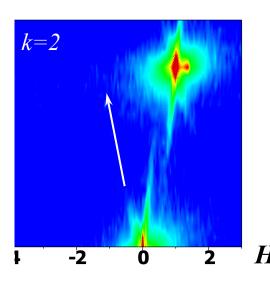




~1/3 ML Ag/Cu(433) (200x200) nm²

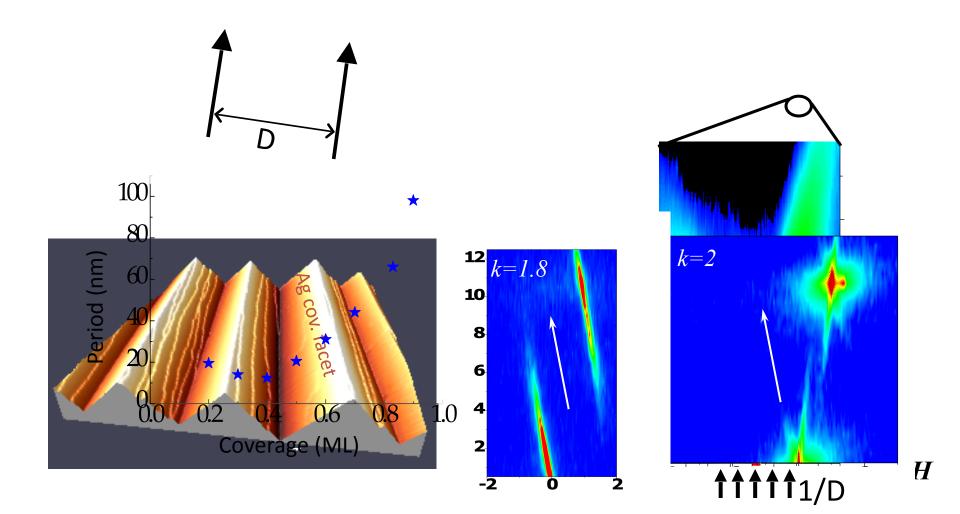




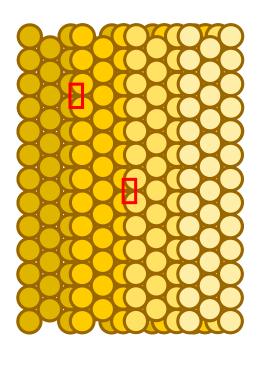


After Ag deposition and annealing

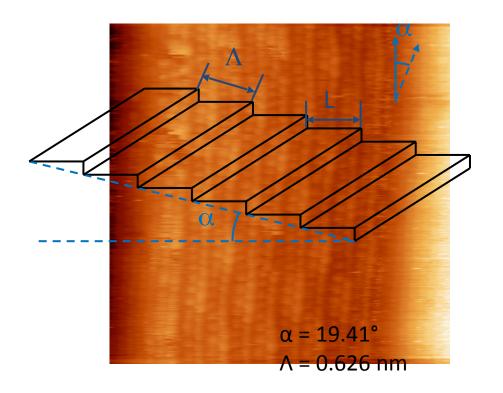
ABSORBATE INDUCED FACETING: X-RAY MEASUREMENTS



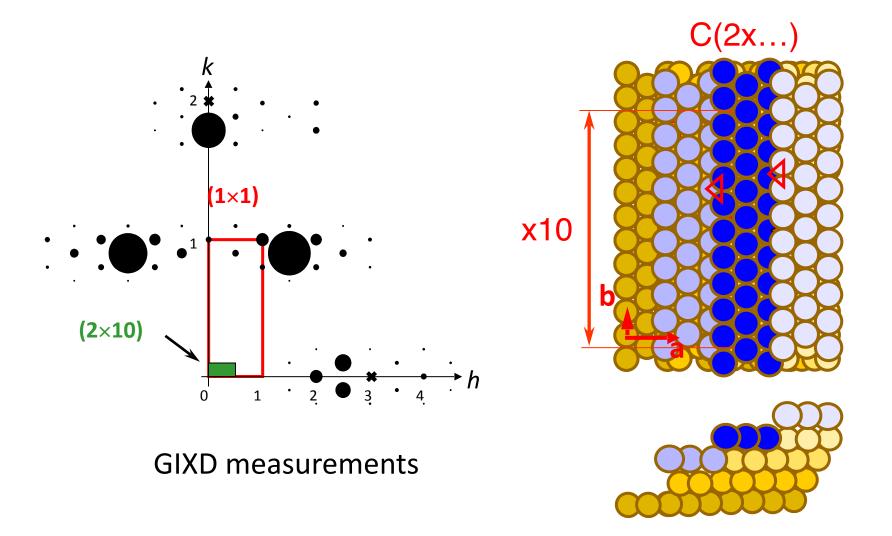
I ML AG/CU(211)



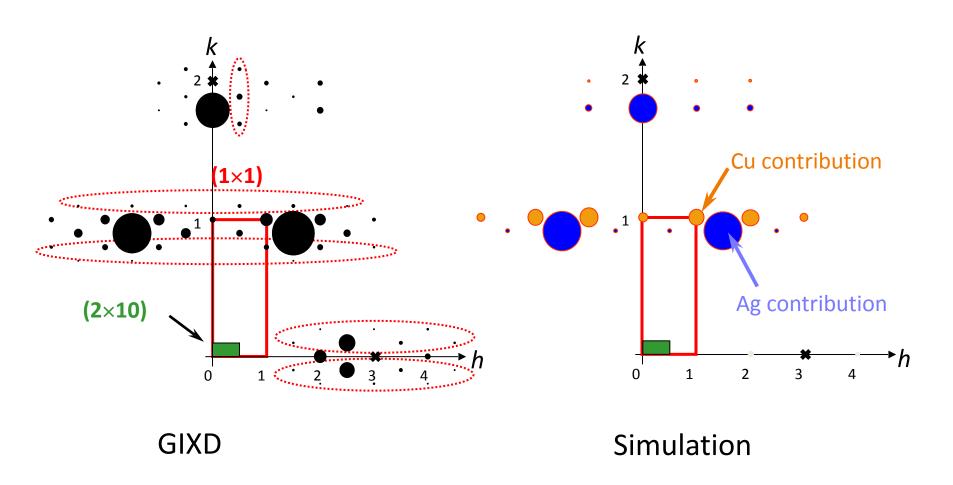




I ML Ag/Cu (211) - reconstruction C(2x10)

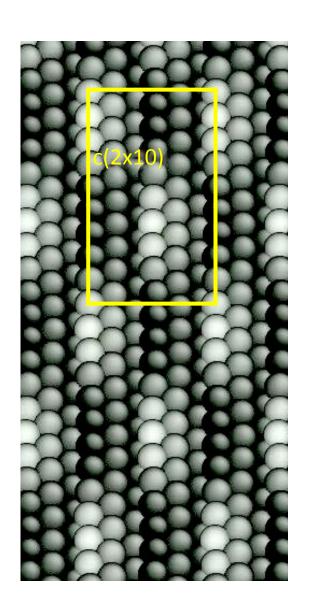


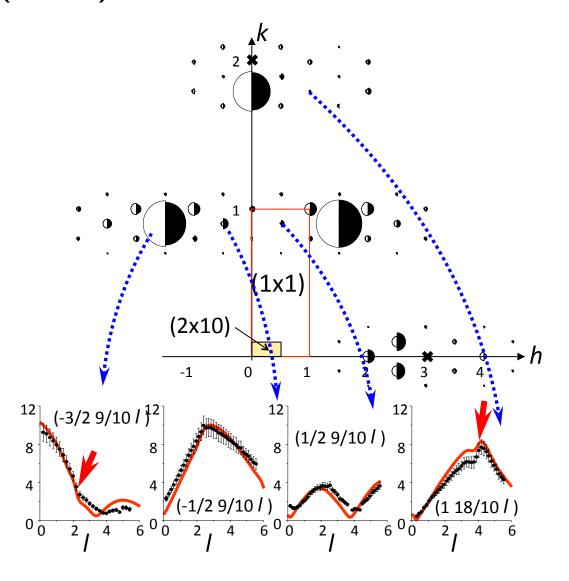
I ML AG/Cu(211) - GIXD



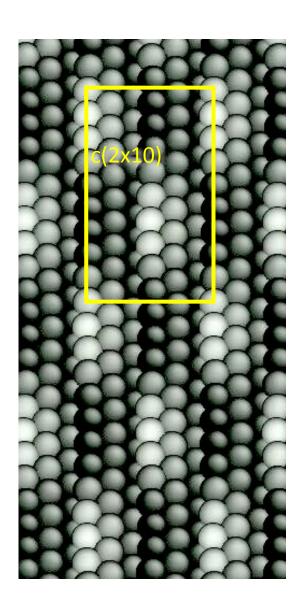
The structure is not relaxed!

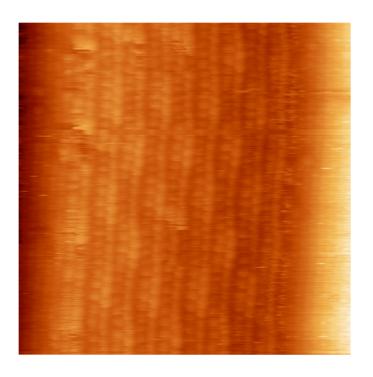
I ML AG/Cu(211) - GIXD ET QMD



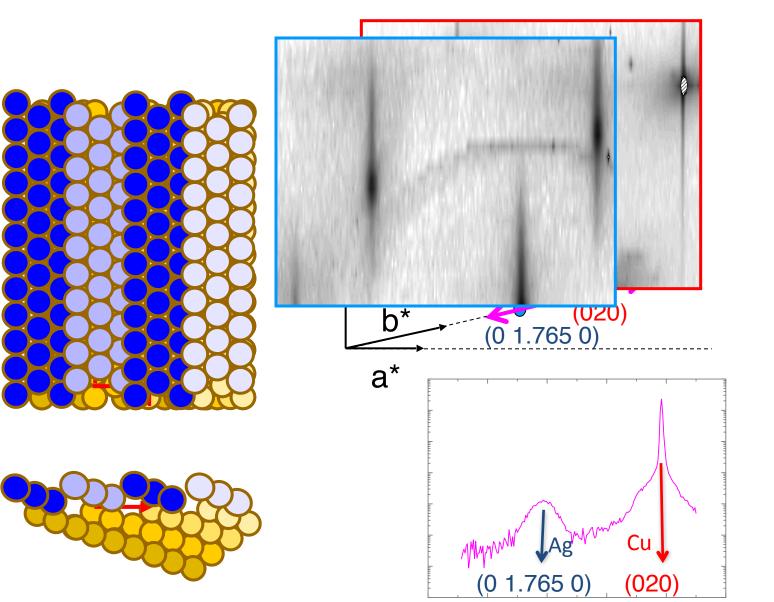


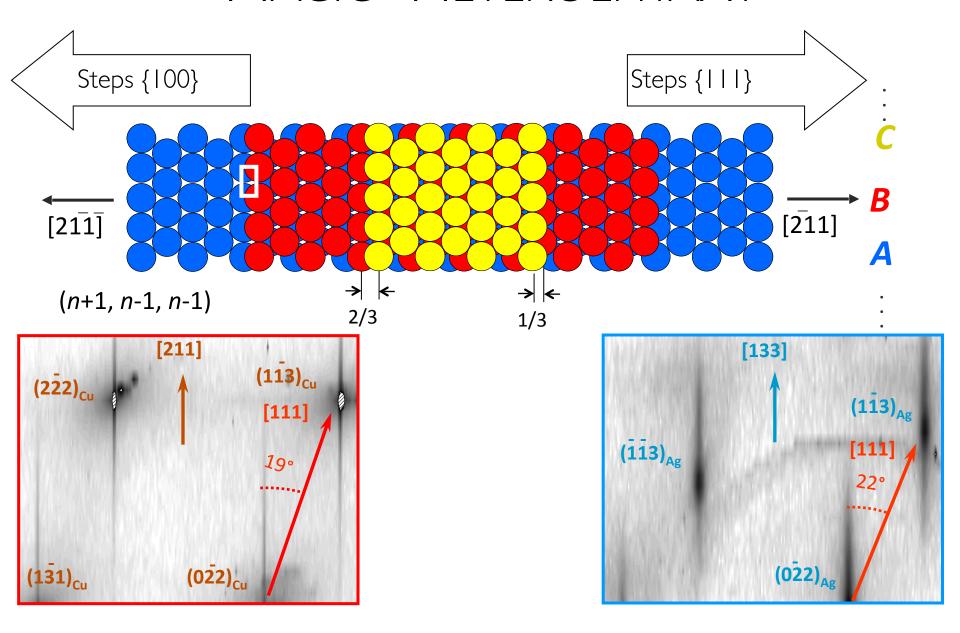
I ML AG/Cu(211) - GIXD & STM

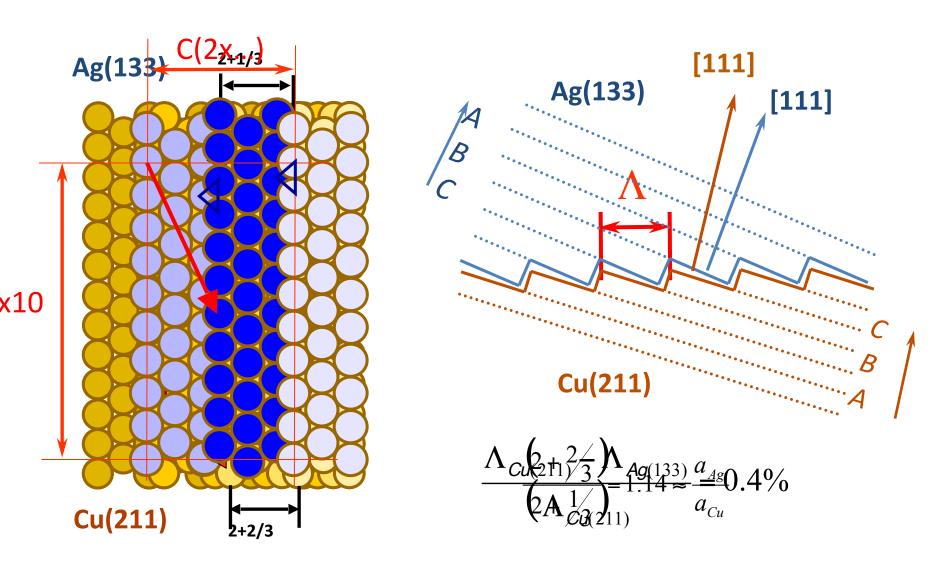




Y. Garreau, A. Coati, A. Zobelli, and J. Creuze Phys. Rev. Lett. 91, 116101

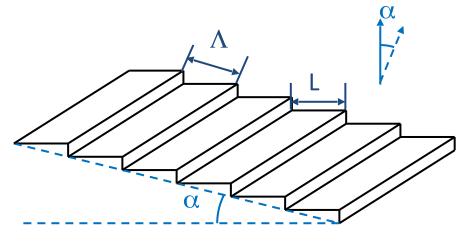


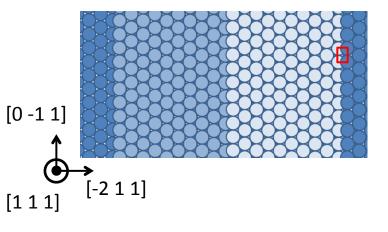




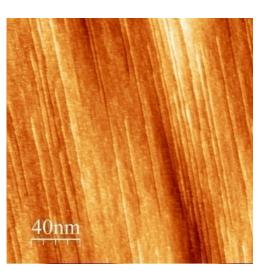
Y. Garreau et al., Phys. Rev. Lett. 91, 116101 (2003)

NI(1199)

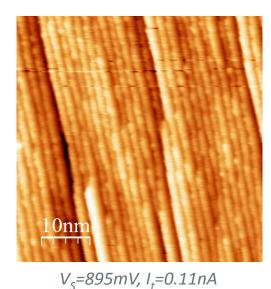




Terrasses : (111) Steps: (001)



 V_{S} =875mV, I_{t} =0.22nA



 $\alpha = 5.57^{\circ}$

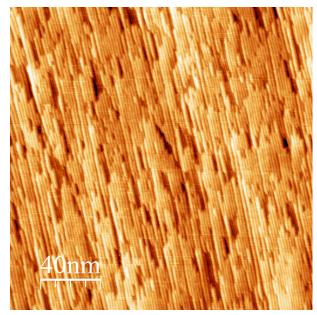
L = 2.1 nm

 $L = 2.09 \pm 0.41 \text{ nm}$

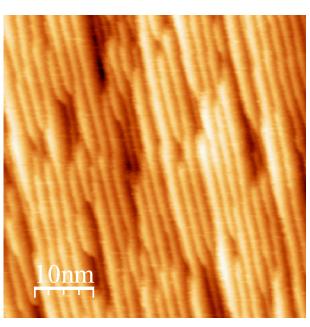
Bellec, A., et al., Physical Review B., 96(8): art.n° 085414. (2017)

AG(4ML)/NI(1199)

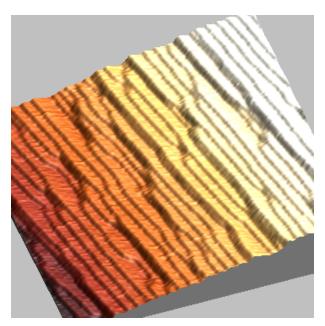
Recuit à 190°C



 $200x200nm^2 - V_s = 0.85V - I_t = 0.15nA$

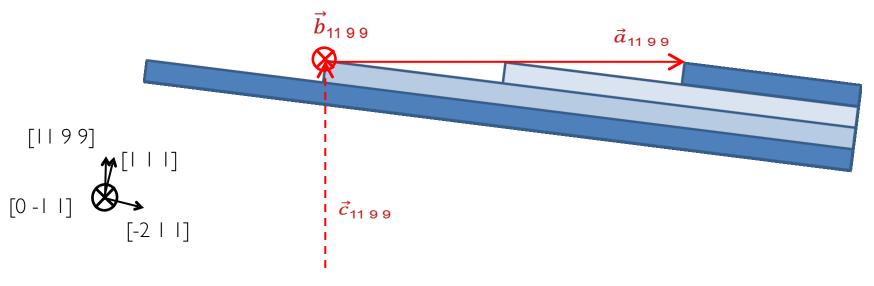


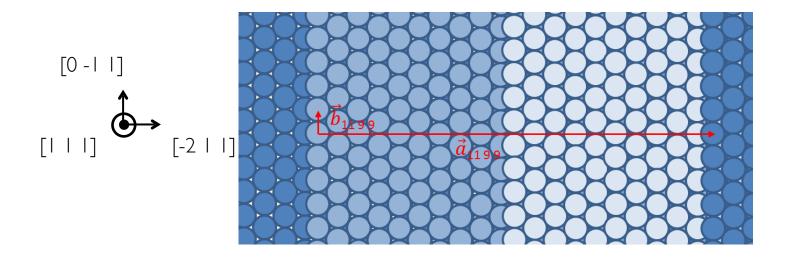
 $50x50nm^2 - V_s = 0.85V - I_t = 0.15nA$



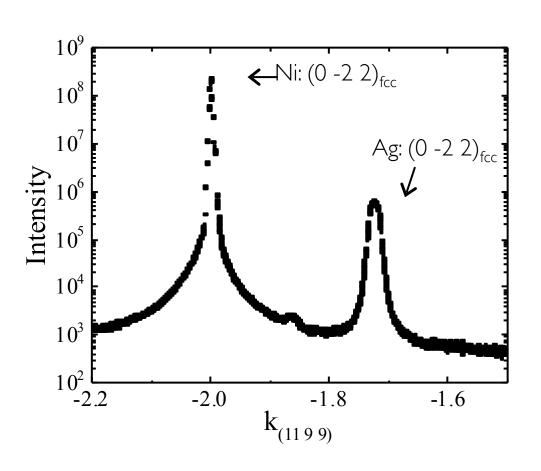
Largeur des terrasses mesurée : L = 2.1 ± 0.3 nm

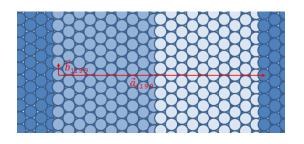
AG/ NI(1199): VICINAL BASIS





ALONG STEP EDGES





Lattice mismatch:

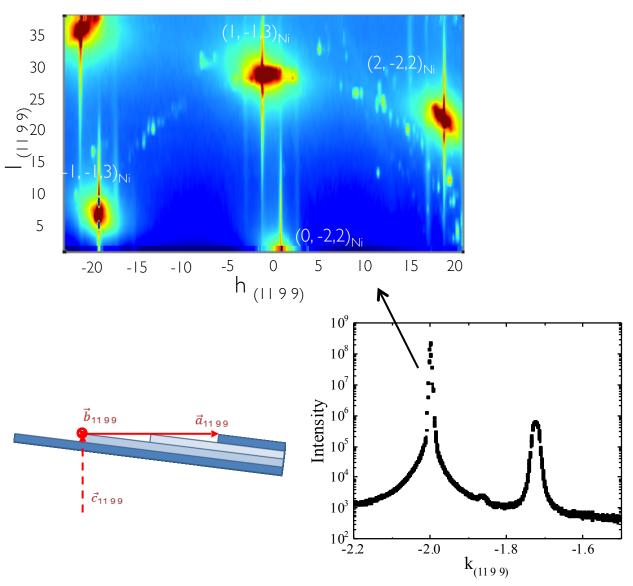
$$\begin{vmatrix} \frac{d_{Ni} - d_{Ag}}{d_{Ni}} - \frac{d_{Ag}}{d_{Ni}} \\ \frac{d_{Ni}}{d_{Ni}} \end{vmatrix} = 0,159$$

Measure:

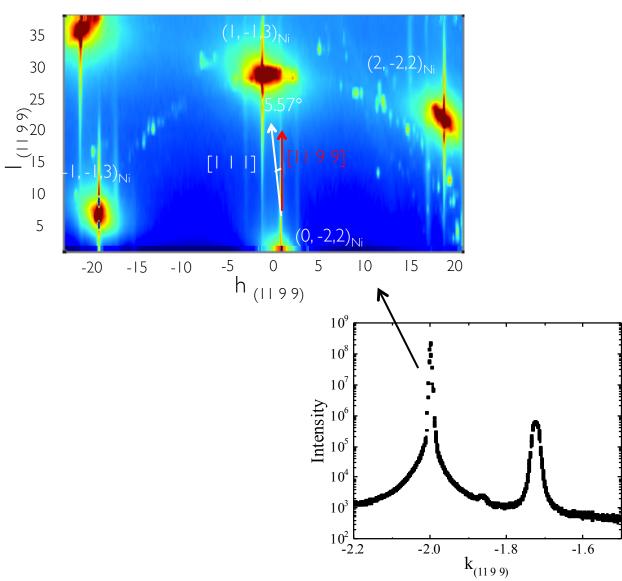
$$\left| \frac{\frac{0}{|Q_{Ni}|^{2} - Q_{Ag}|^{2}}}{\frac{0}{|Q_{Ni}|^{2}}} \right| = 0,161$$

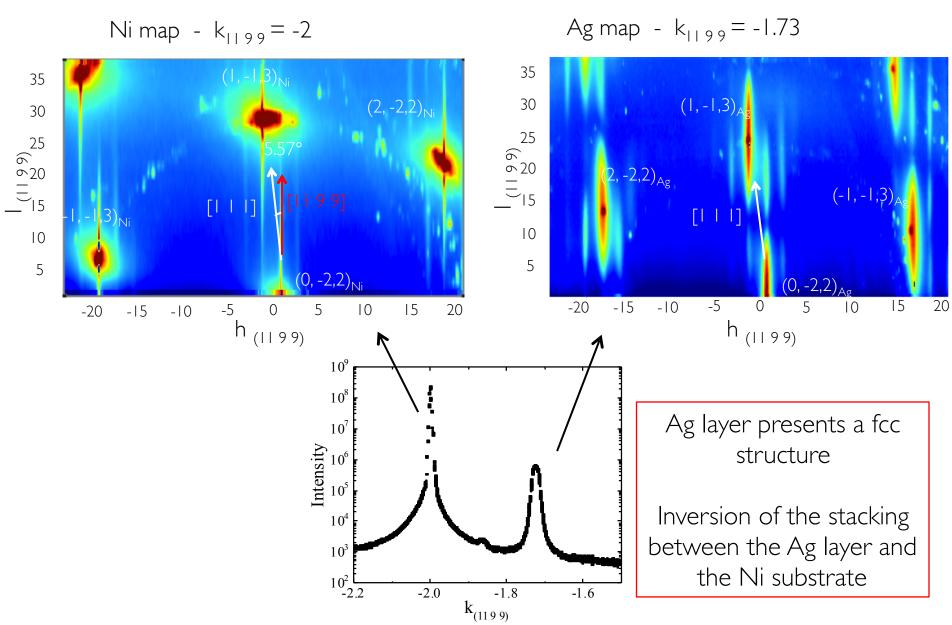
Ag is relaxed along the step edges

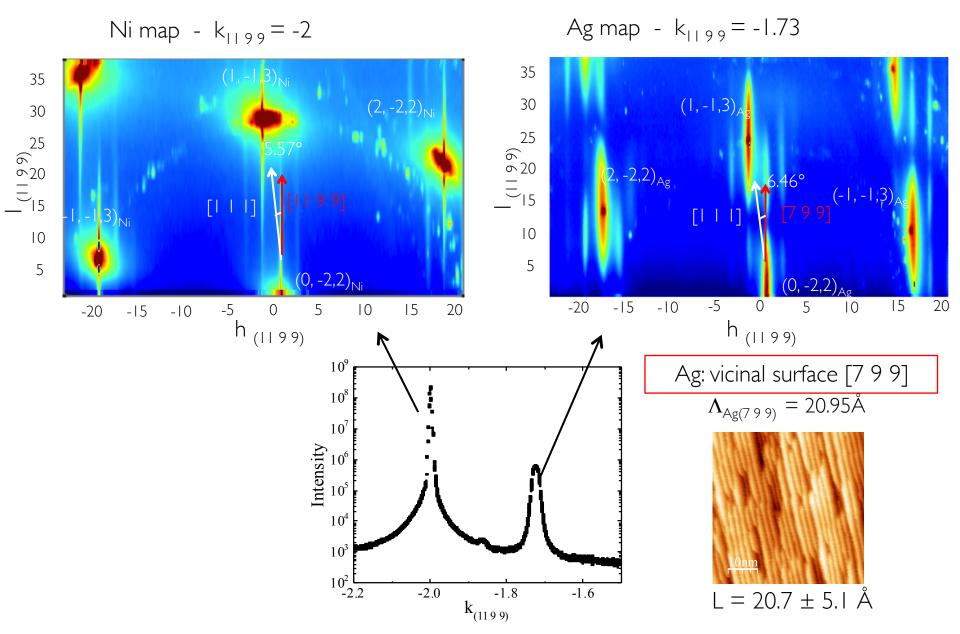
Ni map - $k_{1199} = -2$



Ni map - $k_{1199} = -2$







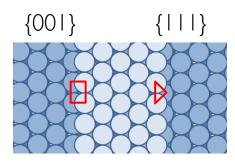
Formation of Ag homogeneous thin film

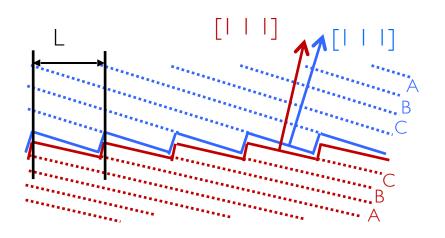
Ni (1199): terraces (111)

steps (001)

<u>Ag (7 9 9)</u>: terraces (111)

steps (III)



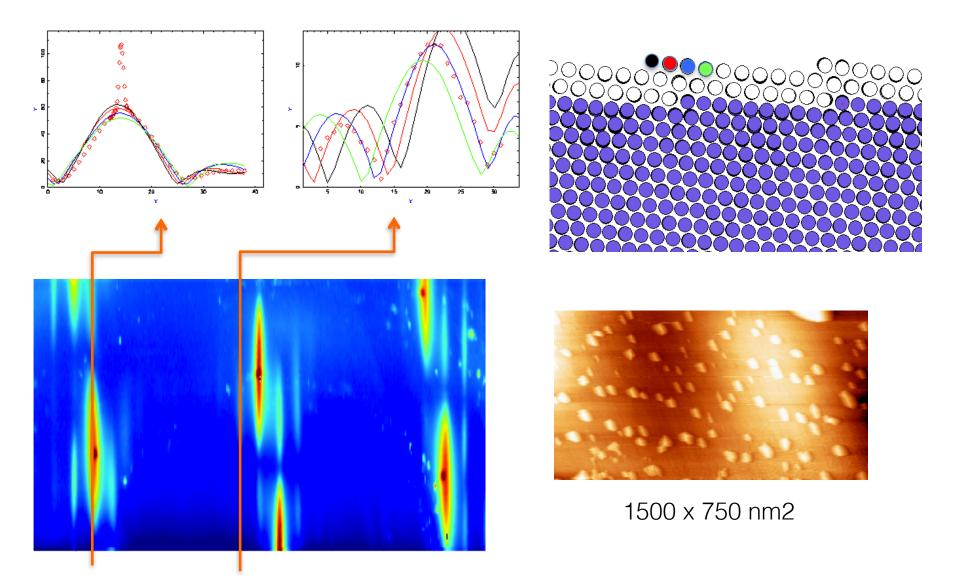


$$\Lambda_{Ag(7 9 9)} = 20.95 \text{Å}$$

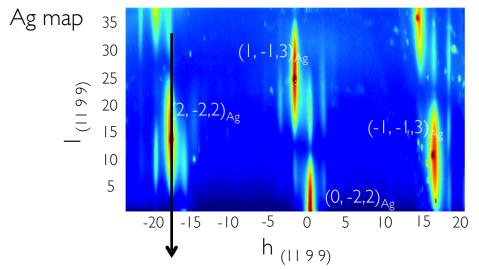
$$\Lambda_{\text{Ni(1199)}} = 20.96 \text{Å}$$

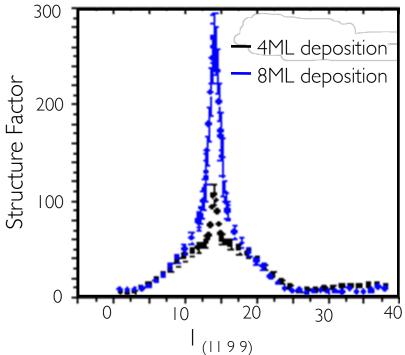
Step period governs the growth of the Ag layer

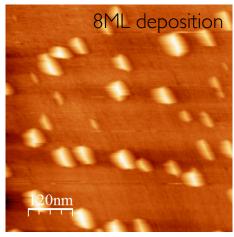
AG ISLANDS



AG ISLANDS







600x600nm²,V=2.4V, I=2.5nA

Island formation on a 2ML Ag(7 9 9) layer

Surface X-ray Scattering

- Reliable quantitative analysis
- Statistical information
- Beyond the surface (buried interfaces...)
- In-situ and operando measurements
- Atomic structure and morphology



SIXS SURFACES AND INTERFACES X-RAY SCATTERING





SixS

Surface Interface X-ray Scattering

Solid surfaces and interfaces structures Nanostructures Self-organised surfaces Original in-situ growths Surface magnetic X-ray diffraction Surfaces in catalytic environment Solid-liquid electrochemical interfaces Buried soft interfaces Liquid-liquid interfaces

GIXD

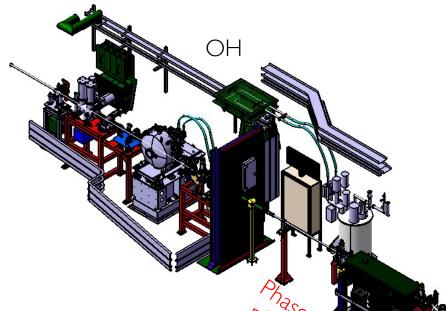
GISAXS

X-ray reflectivity

Anomalous Scattering

Coherent Scattering

Magnetic Scattering



SIXS BEAMLINE OVERVIEW

Two experimental end-stations

EHI

MED: multi-environment diffractometer

UHV: diffractometer coupled to an UHV chamber

U20 undulator Si(111) monochromator Energy range 5-25 keV

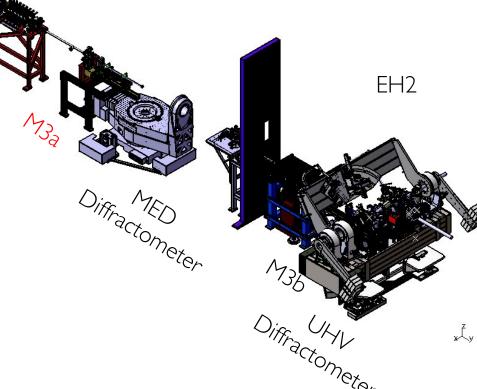
Flux on both experimental stations

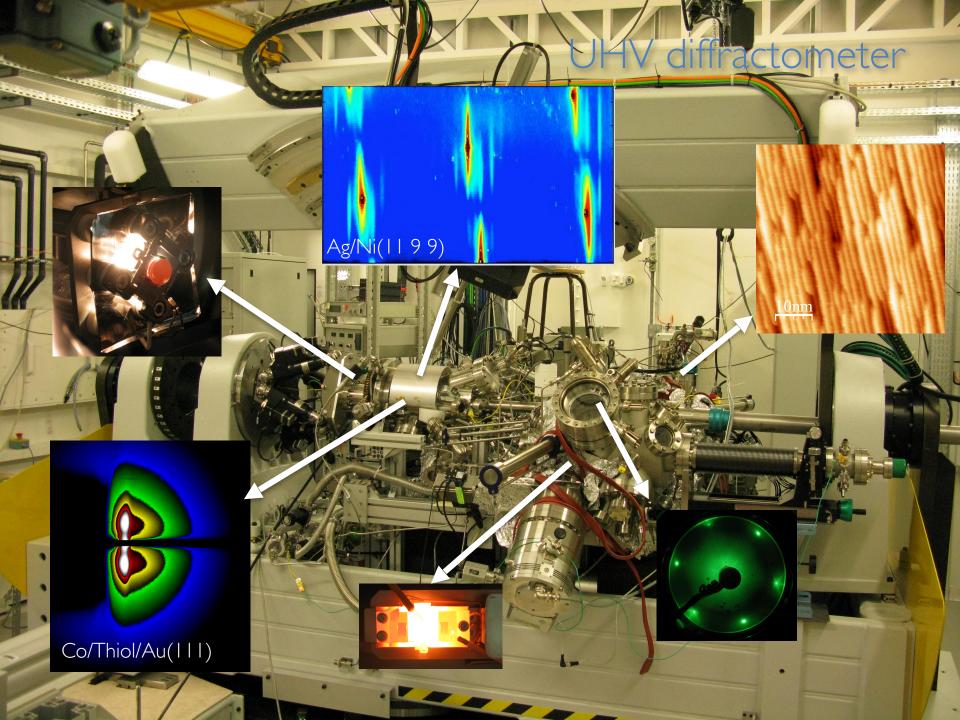
4 10^{13} ph/s with Δ E/E $\sim 10^{-4}$ (6 keV)

3 10^{12} ph/s with $\Delta E/E \sim 2 \cdot 10^{-4} (15 \text{ keV})$

Beam sizes (FWHM):

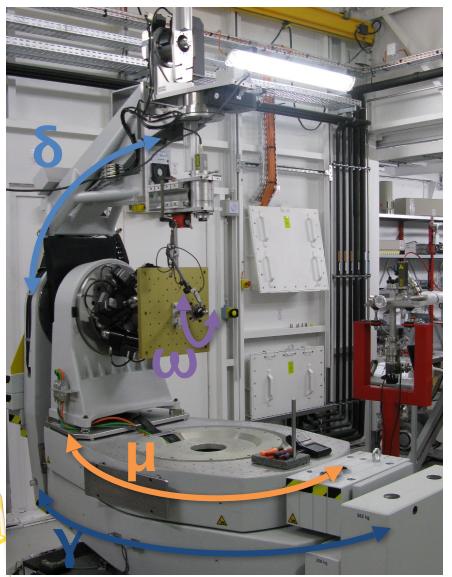
at MED position : $1500(H) \times 25(V) \mu m^2$ at UHV position : $30(H) \times 30(V) \mu m^2$

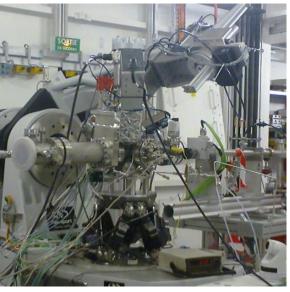




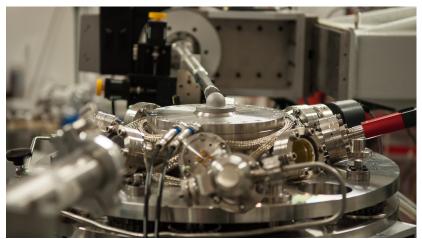
















- Time saved
- Full encoder resolution exploitation
- HKL trajectories > non-linear grouped motors
- Trajectories (XPS controller DC motor with PID)

- Need to integrate properly 2D detectors
- Generalization of the trajectories on other motors

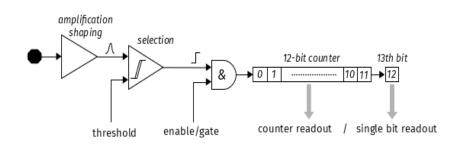


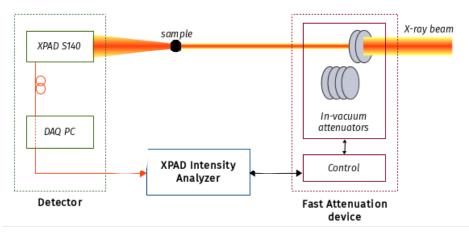


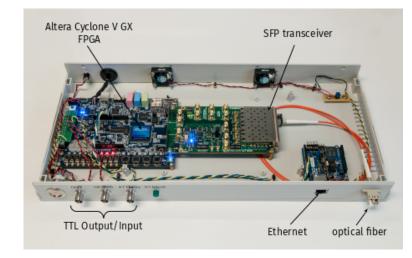
2D detector (XPAD-S140)



Pixel dimensions 130×130 µm² Active surface 240 × 560 pixels 75 × 32 mm² Counter 12 bits + 1 OVF 250 Hz sampling









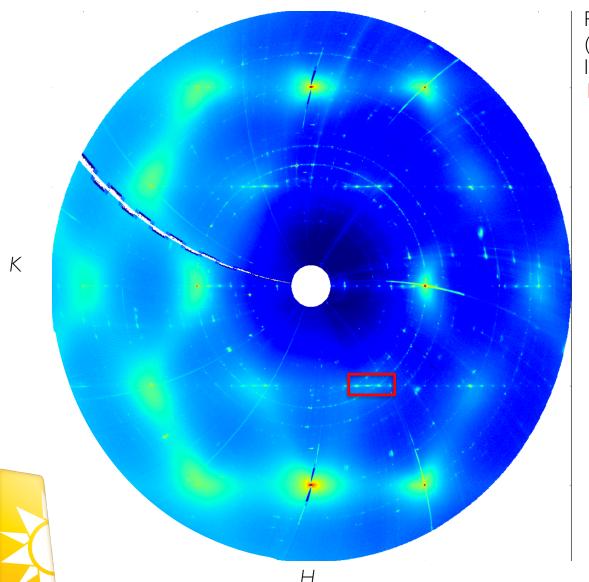
Reciprocal Space Visualisation - BINOCULARS

- Installed on the SOLEIL high performance cluster
 SUMO
 - Data
 - Reduction
 - Representation
 - Projection
 - Build a reciprocal space volume in
 - Q-space
 - (hkl) space
 - Angles space (soon)
 - Intensity integration
 - Python

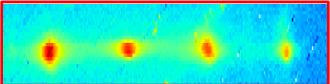


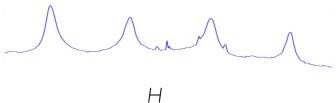






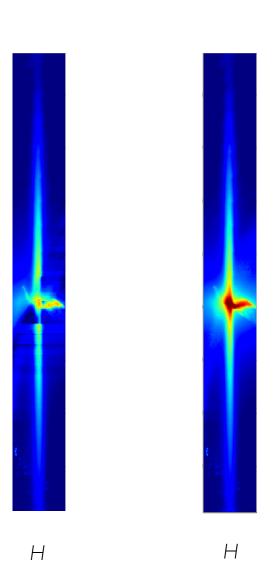
Pentacene/Cu322 (M. Sauvage, K. Muller, A. Kara, et al.) In-plane (hk) – map Ih, 36000 images





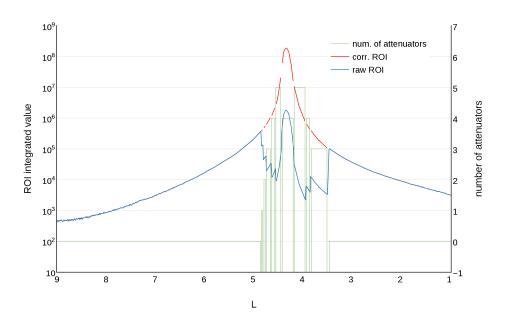
Surface structure Surface periodicity



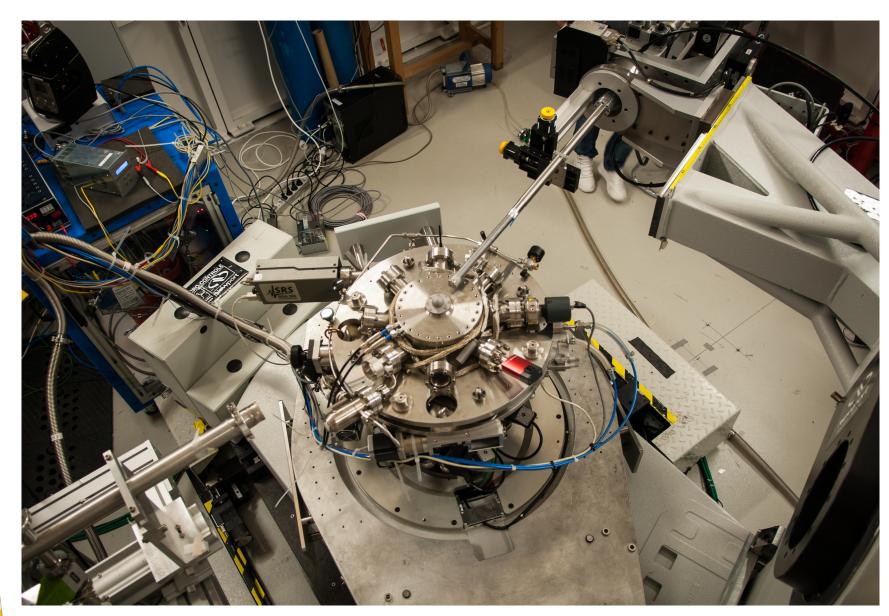


CTR in flyscan

- Less than I min
- projection in the (h l) plane
- Absorbers correction













 $A lina \, VLAD$



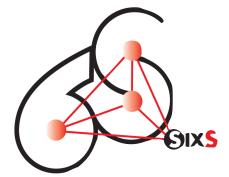
Benjamin VOISIN



Alessandro COATI



Yves GARREAU





Cynthia FOURMENTAL



Corentin CHATELIER



Michèle SAUVAGE



Andrea RESTA



References

Surface diffraction

R. Feidenhans'l, Surface structure determination by X-ray diffraction, Surf. Sci. Reports 10 (1989) 105-188.

I.K. Robinson and D.J. Tweet, Surface X-ray diffraction, Rep. Prog. Phys. 55 (1992) 599-651.